

Supporting Information

Te-Embedded Nanocrystalline PbTe Thick Films: Structure and Thermoelectric Properties Relationship

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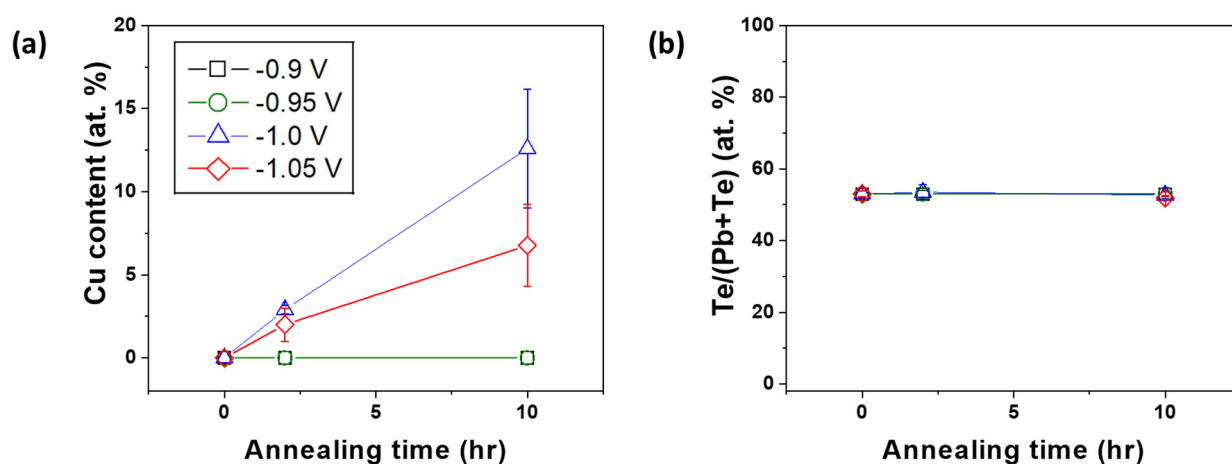


Figure S1. Cu content (a) and ratio of Te/(Pb+Te) (b) as a function of annealing temperature for as-deposited and annealed (2 and 10 hours) PbTe film deposited at -0.9, -0.95, -1.0, -1.05 V vs. Ag/AgCl.

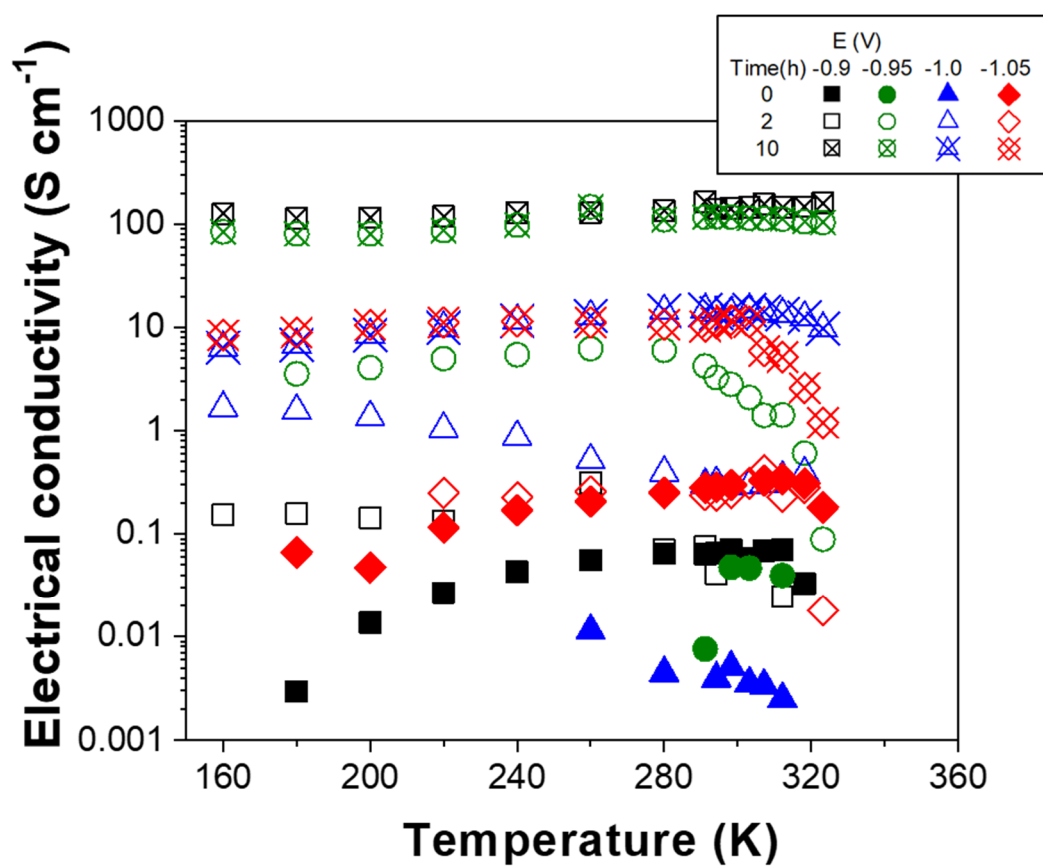


Figure S2. Electrical conductivity as a function of measurement temperature for as-deposited and annealed (2 and 10 hours) PbTe film deposited at -0.9, -0.95, -1.0, -1.05 V vs. Ag/AgCl.

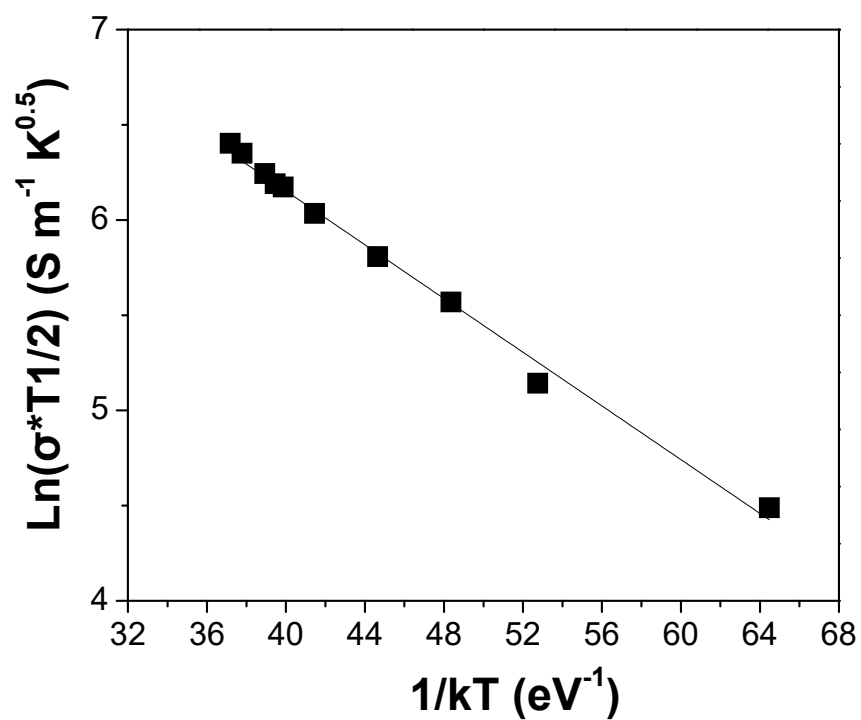


Figure S3. $\ln(\sigma \cdot T^{1/2})$ as a function of $1/kT$ used to extract energy barrier height.